



# TRIPLE IGBT/MOS DRIVER

- THREE POWER IGBT/MOS AND PULSE TRANSFORMER DRIVERS
- CURRENT SENSE COMPARATOR WITH 1ms INHIBITION TIME FUNCTION
- INSTANTANEOUS SIGNAL TRANSMISSION
- 0.6 Amp PER CHANNEL PEAK OUTPUT CURRENT CAPABILITY
- LOW OUTPUT IMPEDANCE TYP : 7Ω at 200mA
- CMOS/LSTTL COMPATIBLE INVERTING INPUT WITH HYSTERESIS
- 4V TO 16V SINGLE SUPPLY OPERATION
- CURRENT AMPLIFIER
- LOW BIAS CURRENT TYP: 1.5mA
- ADJUSTABLE UNDERVOLTAGE LOCKOUT LEVEL
- STAND-BY MODE
- DURING POWER UP NO RANDOM OUTPUT STATE
- ENHANCED LATCH-UP IMMUNITY
- CHANNEL PARALLELING CAPABILITY

# N DIP16 (Plastic Package) (Plastic Micropackage)

### **ORDER CODES**

| Part Number | Temperature   | Package |   |  |
|-------------|---------------|---------|---|--|
| Fait Number | Range         | N       | D |  |
| TD310I      | -40°C, +125°C | •       | • |  |

### **DESCRIPTION**

The TD310 is designed to drive one, two or three Power IGBT/MOS and has driving capability for pulse transformer. So it is perfectly suited to interface control IC with Power Switches in low side or half-bridge configuration.

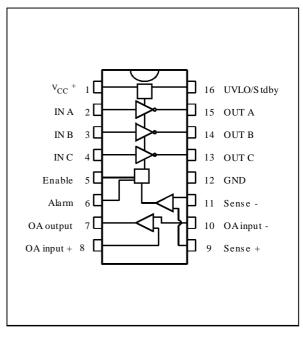
The typical application shown figure 1 implements the TD310 in a pulse controlled half-bridge drive. Positive and negative pulses are applied to the pulse transformer to charge and discharge the IGBT/MOS gate capacitance. More sophisticated secondary circuits provide low impedance gate drive and short-circuit protection as shown in application note n° AN461.

On Figure 2, TD310 is implemented as a low side driver in a typical 3 phase motor drive.

Figure 3 presents a general purpose low side gate drive.

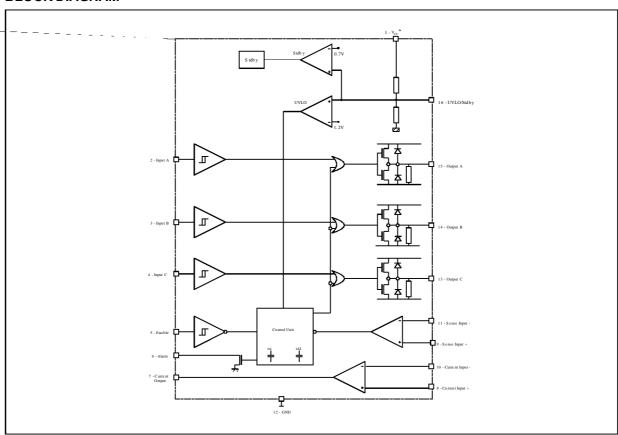
In both case, the current amplifier provides interfacing between a sense resistor and an A/D converter.

### **PIN CONNECTIONS**



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# **BLOCK DIAGRAM**



# **ABSOLUTE MAXIMUM RATINGS**

| Symbol           | Parameter            | Value                   | Unit |
|------------------|----------------------|-------------------------|------|
| Vcc              | Supply Voltage       | 18                      | V    |
| Vi               | Input Voltage        | 0 to V <sub>CC</sub>    | V    |
| Vis              | Sense Input Voltage  | -0.3 to V <sub>CC</sub> | V    |
| Tj               | Junction Temperature | -40 to 150              | °C   |
| T <sub>amb</sub> | Ambient Temperature  | -40 to 125              | °C   |

# **OPERATING CONDITIONS**

| Symbol | Parameter      | Value   | Unit |
|--------|----------------|---------|------|
| Vcc    | Supply Voltage | 4 to 16 | V    |

# **INSTRUCTIONS FOR USE**

- 1  $\;$  The TD310 supply voltage must be decoupled with a  $1\mu F$  min. capacitor.
- 2 If the application involving TD310 requires maximum output current capability, this current must be pulsed: pulse width 1μsec, duty cycle 1% at T<sub>amb</sub>.



# **ELECTRICAL CHARACTERISTICS**

 $V_{CC} = 15V$ ,  $T_{amb} = 25^{\circ}C$  (unless otherwise specified)

| Symbol   | Parameter   | Min. | Тур.                              | Max.       | Unit |
|--|---|------|-----------------------------------|------------|------|
| Icc  | Supply Current with Inputs in High State  |      | 1.5                               | 2          | mA   |
|  | LOGIC INPUT (all inputs)  | •    | ,                                 |            |      |
| VIH  | High Input Voltage  | 2    |                                   |            | V    |
| VIL  | Low Input Voltage   |      |                                   | 0.8        | V    |
| I <sub>IH</sub>  | High Input Current  |      | 10                                |            | pА   |
| I <sub>IL</sub>  | Low Input Current   |      | 10                                |            | pА   |
| t <sub>dH,</sub> t <sub>eH</sub><br>t <sub>dL,</sub> t <sub>eL</sub> | Propagation Delay (10% input to 10% output) Output Rise Output Fall $T_{min.} \le T_{amb} \le T_{max.}$ |      | 200<br>60                         | 400<br>400 | ns   |
| t <sub>ii</sub>  | Input Inhibiting Time   |      | 100                               |            | ns   |
| t <sub>dd</sub>  | Differential Delay Time Between Channels  |      | 20                                |            | ns   |
|  | OUTPUT DRIVERS  |      |                                   |            |      |
| $V_{sod}$  | Sourcing Drop Voltage (A/B/C outputs) I <sub>source</sub> = 200mA                                       |      |                                   | 3          | V    |
| V <sub>sid</sub>   | Sinking Drop Voltage (A/B/C outputs) I <sub>sink</sub> = 200mA  |      |                                   | 5          | V    |
| $V_{\text{dem}}$   | Demagnetising Drop Voltage (A/B/C outputs) I <sub>demag.</sub> = 100mA                                  |      |                                   | 2          | V    |
| R <sub>opd</sub>   | Output Pull Down Resistor   |      | 47                                |            | kΩ   |
|  | ALARM OUTPUT  |      |                                   |            |      |
| Is   | Low Level Sinking Current<br>Vo = 0.8V  | 5    | 35                                |            | mA   |
| I <sub>sh</sub>  | High Level Sinking Current  |      |                                   | 1          | μΑ   |
| t <sub>A</sub>   | Alarm Output : Delay Time to Alarm Fall if Sense Input Triggered  |      |                                   | 500        | ns   |
|  | SENSE INPUT   |      |                                   |            |      |
| $V_{\text{ios}}$   | Input Offset Voltage  |      |                                   | 20         | mV   |
| $t_{Ai}$   | Inhibition Time if Sense Input Triggered  |      | 1                                 |            | ms   |
| ts   | Delay Time to Output Fall if Sense Input Triggered All outputs inhibited                                |      |                                   | 600        | ns   |
| t <sub>si</sub>  | Inhibition Time of Sense Input  |      | 300                               |            | ns   |
| V <sub>shys</sub>  | Sense Hysteresis  |      | 40                                |            | mV   |
|  | OPERATIONAL AMPLIFIER   |      |                                   |            |      |
| V <sub>icm</sub>   | Common Mode Input Voltage Range   | 0    | to V <sub>CC</sub> <sup>+</sup> - | 1.5        | V    |
| Vio  | Input Offset Voltage  |      |                                   | 10         | mV   |
| GBP  | Gain Bandwidth Product  |      | 1                                 |            | MHz  |
| $A_{vd}$   | Open Loop Gain  | 60   |                                   |            | dB   |
| SR   | Slew Rate at Unity Gain $R_L = 100k\Omega$ , $CL = 100pF$ , $V_i = 3 to 7V$                             |      | 0.6                               |            | V/µs |
|  | STAND-BY  |      |                                   |            |      |
| V <sub>stdby</sub>   | Standby Mode Threshold Voltage  | 0.3  |                                   | 1.1        | V    |
| I <sub>stdby</sub>   | Standby Mode Supply Current   |      | 30                                |            | μΑ   |
|  | UNDER VOLTAGE LOCKOUT   |      |                                   |            |      |
| l <sub>adj</sub>   | Under Voltage Level Adjust Current  |      | 1                                 |            | μA/V |
| V <sub>st1</sub>   | Internal Stop Threshold (without external adjustement)  | 10.7 |                                   | 13.3       | V    |
| V <sub>hys</sub>   | Threshold Hysteresis  |      | 0.8                               |            | V    |



# **UVLO/stbdy pin functionning modes**

Due to the wide supply voltage range of the TD310, the UVLO function (Under Voltage Lock Out) is externally adjustable by a resistor bridge.

The bridge rate can be calculated in relation with the expected UVLO protection level as follows:

$$V_{UVLO} \times \frac{R1}{R1+R2} = 1.2V$$
 (where R1 is the lower resistor of the bridge)

The internal resistor sets the default UVLO value to 12V (\*) and might influence the external bridge rate if the values of the external resistors are too high.

The standby threshold value depends of the UVLO value as follows:

$$V_{stdby} = 0.7/1.2 V_{UVLO}$$

Both UVLO and stdby functions can be inhibited by connecting the UVLO/stdby pin to V<sub>CC</sub><sup>+</sup> via a pull up resistor (ex  $150k\Omega$ ).

The following table summarizes the functions of the TD310:

|        | Pin           | 16         | 9/11          | 5          | 2/3/4    | 15/14<br>/13 | 6     | 7/8/10      |             |
|--------|---------------|------------|---------------|------------|----------|--------------|-------|-------------|-------------|
|        | Configuration | UVLO/stdby | Sense+/Sense- | Enabl<br>e | In A/B/C | Out<br>A/B/C | Alarm | Op.<br>Amp. | Consumption |
|        |               |            | +>-           | Х          | Х        | L            | L     |             |             |
| Normal | 1             | Н          | +<-           | Н          | IN       | ĪN           | Н     | OK          | H (1.5mA)   |
|        |               |            |               | L          | Х        | L            | ''    |             |             |
| Stdby  | 2             | L          | +>-           | Х          | X        | ı            | L     | HZ          | L (30μA)    |
| Oldby  |               | _          | +<-           |            |          | _            | Н     | 112         | Ε (σομΑ)    |
| UVLO   | 3             | М          | Х             | Х          | Х        | L            | L     | OK          | Н           |

### Configuration 1: UVLO/stdby = H

The TD310 is in a normal consumption state (1.5mA), the operational amplifier is normally functionning and the buffer outputs are determined by the sense comparator inputs, the enable inputs and the buffer inputs.

### Configuration 2: UVLO/stdby = L

The TD310 is in a low consumption state (standby mode 30µA), the buffer outputs are set to low state and the operational amplifier is in high impedance state.

### Configuration 3: UVLO/stdby = M

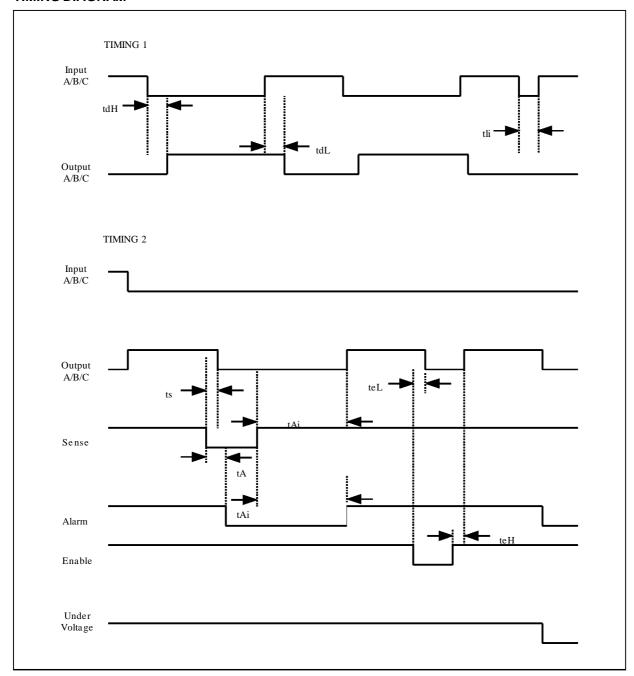
The V<sub>CC</sub> supply voltage is between V<sub>UVLO</sub> and V<sub>stdby</sub> (\*\*). The TD310 remains in a normal consumption state and the operational amplifier is normally functionning but the buffer outputs and the alarm pin are set to low state.

If the UVLO level remains unadjusted, it is recommended to bypass the UVLO/stdby pin with a 1nF capacitor.

(\*) If the UVLO level remains unadjusted, it is recommended to bypass and \$1.25.12., p. (\*\*) If the supply voltage falls below V<sub>stdby</sub>, the TD310 is set in standby mode (configuration 2).



# **TIMING DIAGRAM**



# **TYPICAL APPLICATIONS**

Figure 1 : THREE PHASE MOTOR DRIVE

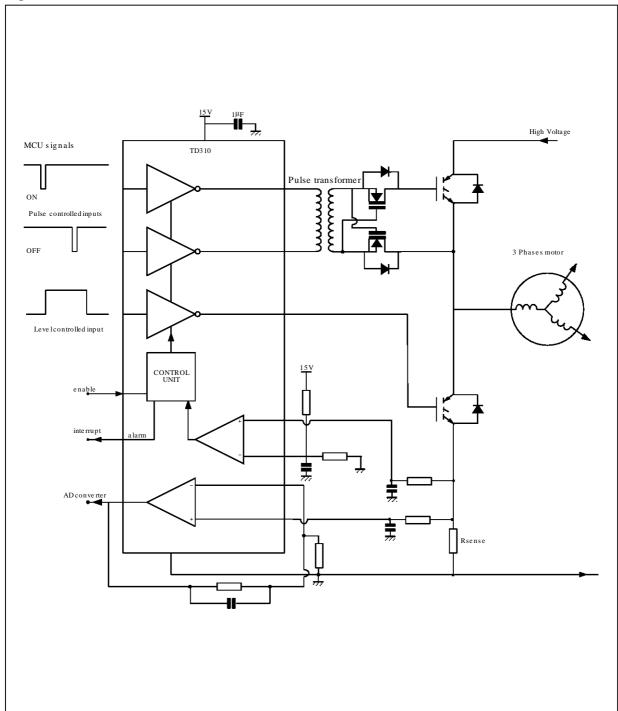


Figure 2: THREE PHASE MOTOR LOW SIDE DRIVE

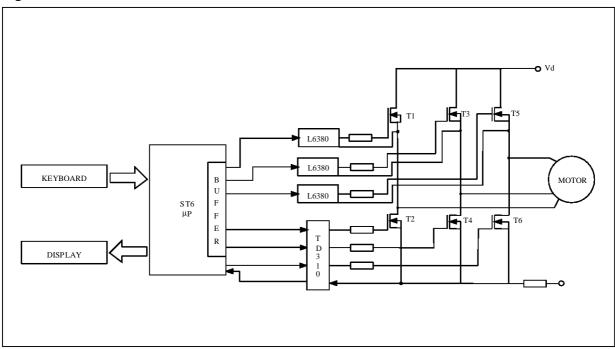
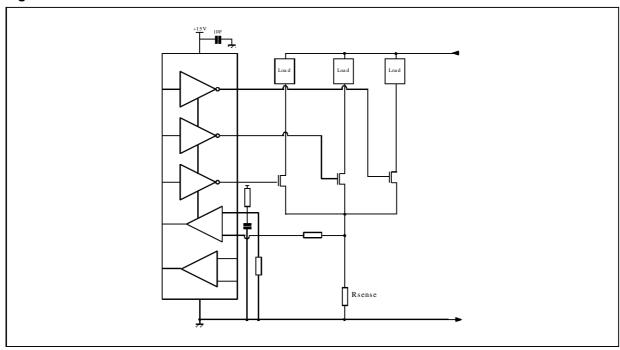
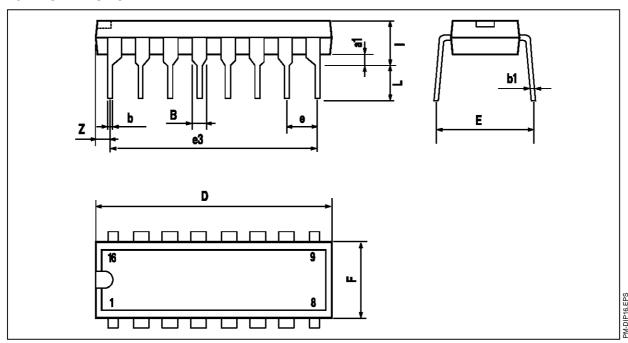


Figure 3: LOW SIDE DRIVE



# **PACKAGE MECHANICAL DATA**

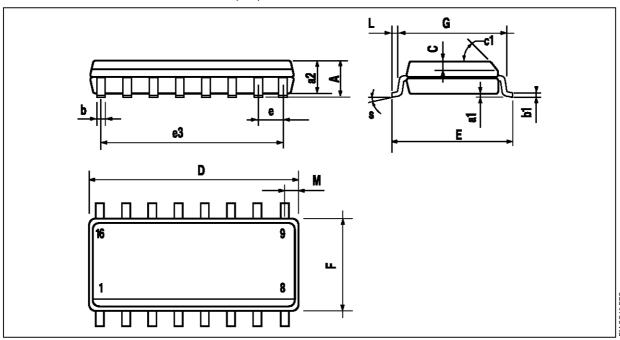
16 PINS - PLASTIC DIP



| Dimensions    |      | Millimeters |      | Inches |       |       |  |
|---------------|------|-------------|------|--------|-------|-------|--|
| Difficitsions | Min. | Тур.        | Max. | Min.   | Тур.  | Max.  |  |
| a1            | 0.51 |             |      | 0.020  |       |       |  |
| В             | 0.77 |             | 1.65 | 0.030  |       | 0.065 |  |
| b             |      | 0.5         |      |        | 0.020 |       |  |
| b1            |      | 0.25        |      |        | 0.010 |       |  |
| D             |      |             | 20   |        |       | 0.787 |  |
| Е             |      | 8.5         |      |        | 0.335 |       |  |
| е             |      | 2.54        |      |        | 0.100 |       |  |
| e3            |      | 17.78       |      |        | 0.700 |       |  |
| F             |      |             | 7.1  |        |       | 0.280 |  |
| i             |      |             | 5.1  |        |       | 0.201 |  |
| L             |      | 3.3         |      |        | 0.130 |       |  |
| Z             |      |             | 1.27 |        |       | 0.050 |  |

### **PACKAGE MECHANICAL DATA**

16 PINS - PLASTIC MICROPACKAGE (SO)



| Dimensions | Millimeters |      |      | Inches |       |       |  |  |
|------------|-------------|------|------|--------|-------|-------|--|--|
|            | Min.        | Тур. | Max. | Min.   | Тур.  | Max.  |  |  |
| Α          |             |      | 1.75 |        |       | 0.069 |  |  |
| a1         | 0.1         |      | 0.2  | 0.004  |       | 0.008 |  |  |
| a2         |             |      | 1.6  |        |       | 0.063 |  |  |
| b          | 0.35        |      | 0.46 | 0.014  |       | 0.018 |  |  |
| b1         | 0.19        |      | 0.25 | 0.007  |       | 0.010 |  |  |
| С          |             | 0.5  |      |        | 0.020 |       |  |  |
| c1         |             |      | 45°  | (typ.) |       |       |  |  |
| D          | 9.8         |      | 10   | 0.386  |       | 0.394 |  |  |
| E          | 5.8         |      | 6.2  | 0.228  |       | 0.244 |  |  |
| е          |             | 1.27 |      |        | 0.050 |       |  |  |
| e3         |             | 8.89 |      |        | 0.350 |       |  |  |
| F          | 3.8         |      | 4.0  | 0.150  |       | 0.157 |  |  |
| G          | 4.6         |      | 5.3  | 0.181  |       | 0.209 |  |  |
| L          | 0.5         |      | 1.27 | 0.020  |       | 0.050 |  |  |
| М          |             |      | 0.62 |        |       | 0.024 |  |  |

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